NSN 5962-01-122-4539

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-0.0/+75.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and 3-state output and programmable and programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
70.00 nanoseconds propagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Yes - demil/mli
Fiig:
A458a0